2.5V/3.3V 1:24 Differential ECL/PECL Clock Driver with Clock Select and Output Enable

Description

The NB100LVEP224 is a low skew 1–to–24 differential clock driver, designed with clock distribution in mind, accepting two clock sources into an input multiplexer. The part is designed for use in low voltage applications which require a large number of outputs to drive precisely aligned low skew signals to their destination. The two clock inputs are differential ECL/PECL and they are selected by the CLK_SEL pin. To avoid generation of a runt clock pulse when the device is enabled/disabled, the Output Enable (\overline{OE}) is synchronous ensuring the outputs will only be enabled/disabled when they are already in LOW state (See Figure 4).

The NB100LVEP224 guarantees low output-to-output skew. The optimal design, layout, and processing minimize skew within a device and from lot to lot. In any differential output, the same bias and termination scheme is required. Unused output pairs should be left unterminated (open) to "reduce power and switching noise as much as possible." Any unused single line of a differential pair should be terminated the same as the used line to maintain balanced loads on the differential driver outputs. The wide VIHCMR specification allows both pair of CLOCK inputs to accept LVDS levels.

The NB100LVEP224, as with most other ECL devices, can be operated from a positive V_{CC} supply in LVPECL mode. This allows the LVEP224 to be used for high performance clock distribution in +3.3 V or +2.5 V systems. Single–ended CLK input operation is limited to a V_{CC} \geq 3.0 V in LVPECL mode, or V_{EE} \leq -3.0 V in NECL mode. In a PECL environment, series or Thevenin line terminations are typically used as they require no additional power supplies. For more information on PECL terminations, designers should refer to Application Note AND8020/D.

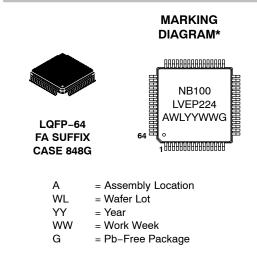
Features

- 20 ps Typical Output-to-Output Skew
- 75 ps Typical Device-to-Device Skew
- Maximum Frequency > 1 GHz
- 650 ps Typical Propagation Delay
- LVPECL Mode Operating Range: V_{CC} = 2.375 V to 3.8 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -2.375 V to -3.8 V



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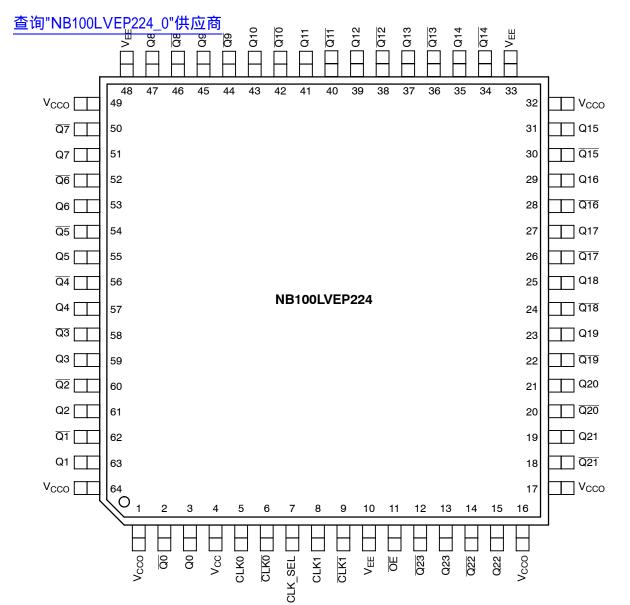
*For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

- Internal Input Pulldown Resistors
- Q Output will Default Low with Inputs Open or at VEE
- Thermally Enhanced 64-Lead LQFP
- CLOCK Inputs are LVDS–Compatible; Requires External 100 Ω LVDS Termination Resistor
- Pb-Free Packages are Available*

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



All V_{CC} , V_{CCO} , and V_{EE} pins must be externally connected to appropriate Power Supply to guarantee proper operation. The thermally conductive exposed pad on package bottom (see package case drawing) must be attached to a heat-sinking conduit, capable of transferring 1.2 Watts. This exposed pad is electrically connected to V_{EE} internally.



Table 1. PIN DESCRIPTION

| PIN | FUNCTION |
|------------------------------------|------------------------------|
| CLK0*, CLK0** | ECL Differential Input Clock |
| CLK1*, CLK1** | ECL Differential Input Clock |
| CLK_SEL* | ECL Input CLK Select |
| OE* | ECL Output Enable |
| Q0-Q23, Q0-Q23 | ECL Differential Outputs |
| V _{CC} , V _{CC0} | Positive Supply |
| V _{EE} *** | Negative Supply |

* Pins will default LOW when left open.

** Pins will default HIGH when left open.

*** The thermally conductive exposed pad on the bottom of the package is electrically connected to V_{EE} internally.

Table 2. FUNCTION TABLE

| OE (1) | CLK_SEL | Q0-Q23 | Q0-Q23 |
|--------|---------|------------------------|------------------------|
| ΤΤΓ | | CLK0 CLK1 L L | CLK0 CLK1 H H |

1. The OE (Output Enable) signal is synchronized with the falling edge of the LVPECL_CLK signal.

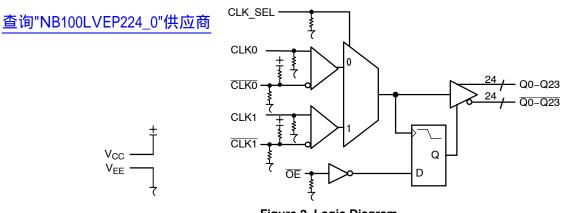


Figure 2. Logic Diagram

Table 3. ATTRIBUTES

| Characterist | Value | | | |
|---------------------------------------|---|-----------|----------------------|--|
| Internal Input Pulldown Resistor | 75 kΩ | | | |
| Internal Input Pullup Resistor | | 37. | 5 kΩ | |
| ESD Protection | Human Body Model Machine Model Charged Device Model | > 1 | 2 kV 50 V 2 kV | |
| Moisture Sensitivity, Indefinite Time | Out of Drypack (Note 2) | Pb Pkg | Pb-Free Pkg | |
| | LQFP-64 | Level 2 | Level 3 | |
| Flammability Rating | Oxygen Index: 28 to 34 | UL 94 V-0 | @ 0.125 in | |
| Transistor Count | | 654 D | Devices | |
| Meets or exceeds JEDEC Spec EIA | JESD78 IC Latchup Test | | | |

2. For additional information, refer to Application Note AND8003/D.

Table 4. MAXIMUM RATINGS

| Symbol | Parameter | Condition 1 | Condition 2 | Rating | Unit |
|------------------|---|--|--|-------------------|--------------|
| V _{CC} | PECL Mode Power Supply | $V_{EE} = 0 V$ | | 6 | V |
| V_EE | NECL Mode Power Supply | $V_{CC} = 0 V$ | | -6 | V |
| VI | PECL Mode Input Voltage NECL Mode Input Voltage | V _{EE} = 0 V V _{CC} = 0 V | $V_{I} \leq V_{CC} \\ V_{I} \geq V_{EE}$ | 6 to 0 –6 to 0 | V |
| T _A | Operating Temperature Range | | | -40 to +85 | °C |
| T _{stg} | Storage Temperature Range | | | –65 to +150 | °C |
| θ_{JA} | Thermal Resistance (Junction-to-Ambient) (See Application Information) | 0 lfpm 500 lfpm | 64 LQFP 64 LQFP | 35.6 30 | °C/W °C/W |
| θJC | Thermal Resistance (Junction-to-Case) (See Application Information) | 0 lfpm 500 lfpm | 64 LQFP 64 LQFP | 3.2 6.4 | °C/W °C/W |
| T _{sol} | Wave Solder Pb Pb-Free | | | 265 265 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

| | | | −40°C | | | 25°C | | | 85°C | | |
|-----------------|--|-------------|--------------|------|-------------|------|------|-------------|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| I _{EE} | Power Supply Current | 130 | 160 | 195 | 135 | 165 | 200 | 140 | 165 | 205 | mA |
| V _{OH} | Output HIGH Voltage (Note 4) | 1355 | 1480 | 1605 | 1355 | 1480 | 1605 | 1355 | 1480 | 1605 | mV |
| V _{OL} | Output LOW Voltage (Note 4) | 555 | 680 | 900 | 555 | 680 | 900 | 555 | 680 | 900 | mV |
| V _{IH} | Input HIGH Voltage (Single-Ended) (Note 5) | 1335 | | 1620 | 1335 | | 1620 | 1275 | | 1620 | mV |
| V _{IL} | Input LOW Voltage (Single-Ended) (Note 5) | 555 | | 900 | 555 | | 900 | 555 | | 900 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 6) CLK/CLK | 1.2 | | 2.5 | 1.2 | | 2.5 | 1.2 | | 2.5 | v |
| I _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| IIL | Input LOW Current CLK CLK | 0.5 -150 | | | 0.5 -150 | | | 0.5 -150 | | | μA |

查帕哈瓦也VPECV PC224APAQTEPASTICS V_{CC} = 2.5 V; V_{EE} = 0 V (Note 3)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

3. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary + 0.125 V to -1.3 V.

4. All outputs loaded with 50 Ω to \dot{V}_{CC} – 2.0 V.

5. Do not use V_{BB} at VCC < 3.0 V.

 V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

| | | | -40°C | | | 25°C | | | 85°C | | |
|-----------------|--|-------------|-------|------|-------------|------|------|-------------|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| I _{EE} | Power Supply Current | 140 | 165 | 195 | 145 | 175 | 205 | 145 | 175 | 210 | mA |
| V _{OH} | Output HIGH Voltage (Note 8) | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | mV |
| V _{OL} | Output LOW Voltage (Note 8) | 1355 | 1480 | 1700 | 1355 | 1480 | 1700 | 1355 | 1480 | 1700 | mV |
| V _{IH} | Input HIGH Voltage (Single-Ended) (Note 9) | | | 2420 | 2135 | | 2420 | 2135 | | 2420 | mV |
| V _{IL} | Input LOW Voltage (Single-Ended) (Note 9) | 1355 | | 1700 | 1355 | | 1700 | 1355 | | 1700 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 10) (Figure 5) | 1.2 | | 3.3 | 1.2 | | 3.3 | 1.2 | | 3.3 | V |
| I _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μΑ |
| IIL | Input LOW Current CLK CLK | 0.5 -150 | | | 0.5 -150 | | | 0.5 -150 | | | μΑ |

Table 6. LVPECL DC CHARACTERISTICS V_{CC} = 3.3 V; V_{EE} = 0 V (Note 7)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

7. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.925 V to –0.5 V.

8. All outputs loaded with 50 Ω to V_{CC} – 2.0 V.

9. Single ended input operation is limited $V_{CC} \ge 3.0$ V in LVPECL mode.

10. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

| | | | −40°C | | | 25°C | | | 85°C | | |
|-----------------|--|-----------------|--------------|------------|-----------------|------------|------------|-----------------|------------|------------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| I _{EE} | Power Supply Current $V_{EE} = -2.5 V$ $V_{EE} = -3.3 V$ | 130 140 | 160 165 | 195 195 | 135 145 | 165 175 | 200 205 | 140 145 | 165 175 | 205 210 | mA |
| V _{OH} | Output HIGH Voltage (Note 12) | -1145 | -1020 | -895 | -1145 | -1020 | -895 | -1145 | -1020 | -895 | mV |
| V _{OL} | Output LOW Voltage (Note 12) | -1945 | -1820 | -1600 | -1945 | -1820 | -1600 | -1945 | -1820 | -1600 | mV |
| V _{IH} | Input HIGH Voltage (Single-Ended) (Note 13) | -1165 | | -880 | -1165 | | -880 | -1165 | | -880 | mV |
| V _{IL} | Input LOW Voltage (Single-Ended) (Note 13) | -1945 | | -1600 | -1945 | | -1600 | -1945 | | -1600 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 14) (Figure 5) | V _{EE} | + 1.2 | 0.0 | V _{EE} | + 1.2 | 0.0 | V _{EE} | + 1.2 | 0.0 | V |
| I _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| IIL | Input LOW Current CLK CLK | 0.5 -150 | | | 0.5 -150 | | | 0.5 -150 | | | μΑ |

29 / KINE CHARAO TERISTICS V_{CC} = 0 V, V_{EE} = -2.375 V to -3.8 V (Note 11)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

11. Input and output parameters vary 1:1 with $V_{\mbox{CC}}.$

12. All outputs loaded with 50 Ω to V_{CC} – 2.0 V.

13. Single ended input operation is limited V_{EE} ≤ -3.0 V in NECL mode.

14. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

| | | | -40°C | | | 25°C | | | 85°C | | |
|--------------------------------------|--|-------------------|-------------------|------------|-------------------|-------------------|------------|-------------------|-------------------|--------------|----------------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| V _{Opp} | | 600 600 600 | 750 750 700 | | 600 600 525 | 725 725 650 | | 575 550 400 | 700 650 525 | | mV mV mV |
| t _{PLH} t _{PHL} | Propagation Delay (Differential Configuration) CLKx-Qx CLK_SELx-Qx | 500 600 | 600 700 | 700 800 | 550 650 | 650 800 | 750 900 | 650 750 | 750 850 | 1000 1150 | ps ps |
| t _{skew} | Within-Device Skew (Note 16) Device-to-Device Skew (Note 17) | | 20 50 | 40 300 | | 20 50 | 40 300 | | 35 100 | 60 300 | ps ps |
| t _{JITTER} | Random Clock Jitter (Figure 3) (RMS) | | 1 | 5 | | 1 | 5 | | 1 | 5 | ps |
| V _{PP} | Input Swing (Differential Configuration) (Note 19) (Figure 5) | 200 | 800 | 1200 | 200 | 800 | 1200 | 200 | 800 | 1200 | mV |
| t _S | OE Set Up Time (Note 18) | 200 | | | 200 | | | 200 | | | ps |
| t _H | OE Hold Time | 200 | | | 200 | | | 200 | | | ps |
| t _r /t _f | Output Rise/Fall Time (20%-80%) | 100 | 200 | 300 | 100 | 200 | 300 | 150 | 250 | 350 | ps |

Table 8. AC CHARACTERISTICS V_{CC} = 2.375 V to 3.8 V; V_{EE} = 0 V (Note 15)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

15. Measured with PECL 750 mV source, 50% duty cycle clock source. All outputs loaded with 50 Ω to V_{CC} – 2 V.

16. Skew is measured between outputs under identical transitions and conditions on any one device.

17. Device-to-Device skew for identical transitions at identical V_{CC} levels.

18. OE Set Up Time is defined with respect to the falling edge of the clock. OE High-to-Low transition ensures outputs remain disabled during the next clock cycle. OE Low-to-High transition enables normal operation of the next input clock.

19. V_{PP} is the differential input voltage swing required to maintain AC characteristics including t_{PD} and device-to-device skew.

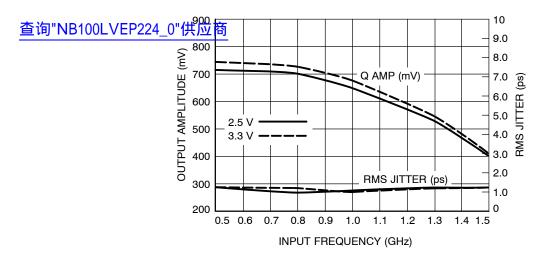


Figure 3. Output Amplitude (V_{OPP}) versus Input Frequency and Random Clock Jitter (t_{JITTER})

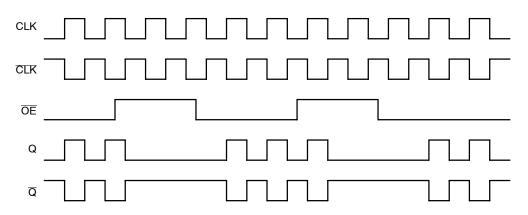


Figure 4. Output Enable (OE) Timing Diagram

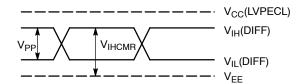


Figure 5. LVPECL Differential Input Levels

APPLICATIONS INFORMATION

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Using the thermally enhanced package of the NB100LVEP224

The NB100LVEP224 uses a thermally enhanced 64-lead LQFP package. The package is molded so that a portion of the leadframe is exposed at the surface of the package bottom side. This exposed metal pad will provide the low thermal impedance that supports the power consumption of the NB100LVEP224 high-speed bipolar integrated circuit and will ease the power management task for the system design. In multilayer board designs, a thermal land pattern on the printed circuit board and thermal vias are recommended to maximize both the removal of heat from the package and electrical performance of the NB100LVEP224. The size of the land pattern can be larger, smaller, or even take on a different shape than the exposed pad on the package. However, the solderable area should be at least the same size and shape as the exposed pad on the package. Direct soldering of the exposed pad to the thermal land will provide an efficient thermal conduit. The thermal vias will connect the exposed pad of the package to internal copper planes of the board. The number of vias, spacing, via diameters and land pattern design depend on the application and the amount of heat to be removed from the package.

Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern.

The recommended thermal land design for NB100LVEP224 applications on multi-layer boards comprises a 4 X 4 thermal via array using a 1.2 mm pitch as shown in Figure 6 providing an efficient heat removal path.

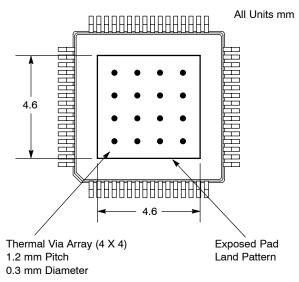


Figure 6. Recommended Thermal Land Pattern

The via diameter should be approximately 0.3 mm with 1 oz. copper via barrel plating. Solder wicking inside the via may result in voiding during the solder process and must be avoided. If the copper plating does not plug the vias, stencil print solder paste onto the printed circuit pad. This will supply enough solder paste to fill those vias and not starve the solder joints. The attachment process for the exposed pad package is equivalent to standard surface mount packages. Figure 7, "Recommended solder mask openings", shows a recommended solder mask opening with respect to a 4 X 4 thermal via array. Because a large solder mask opening may result in a poor rework release, the opening should be subdivided as shown in Figure 7. For the nominal package standoff of 0.1 mm, a stencil thickness of 5 to 8 mils should be considered.

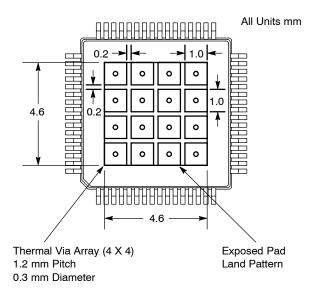


Figure 7. Recommended Solder Mask Openings

Proper thermal management is critical for reliable system operation. This is especially true for high–fanout and high output drive capability products.

For thermal system analysis and junction temperature calculation the thermal resistance parameters of the package is provided:

| Table 9 | 9. Thermal | Resistance | * |
|---------|------------|------------|---|
|---------|------------|------------|---|

| lfpm | θJA °C/W | θJC °C/W |
|------|----------|----------|
| 0 | 35.6 | 3.2 |
| 100 | 32.8 | 4.9 |
| 500 | 30.0 | 6.4 |

* Junction to ambient and Junction to board, four-conductor layer test board (2S2P) per JESD 51-8

These recommendations are to be used as a guideline, only. It is therefore recommended that users employ sufficient thermal modeling analysis to assist in applying the general recommendations to their particular application to assure adequate thermal performance. The exposed pad of the NB100LVEP224 package is electrically shorted to the substrate of the integrated circuit and V_{EE} . The thermal land should be electrically connected to V_{EE} .

| Device | Package | Shipping [†] |
|------------------|----------------------|-----------------------|
| NB100LVEP224FA | LQFP-64 | 160 Units / Tray |
| NB100LVEP224FAG | LQFP-64 (Pb-Free) | 160 Units / Tray |
| NB100LVEP224FAR2 | LQFP-64 | 1500 / Tape & Reel |
| NB100LVEP224FARG | LQFP-64 (Pb-Free) | 1500 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

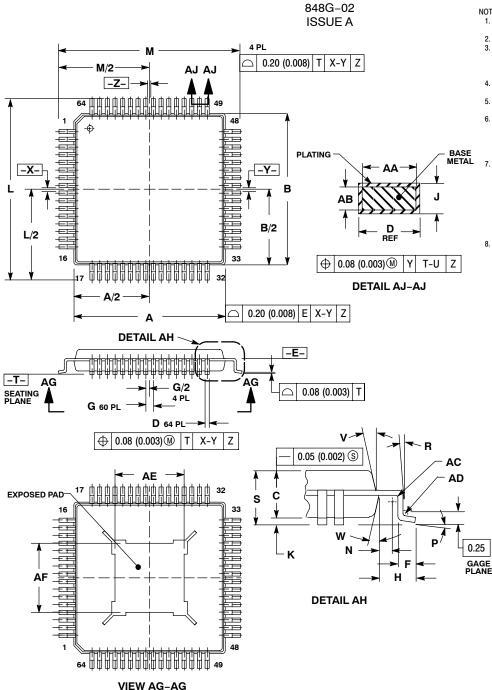
Resource Reference of Application Notes

| AN1405/D | - | ECL Clock Distribution Techniques |
|-----------|---|---|
| AN1406/D | - | Designing with PECL (ECL at +5.0 V) |
| AN1503/D | - | ECLinPS [™] I/O SPiCE Modeling Kit |
| AN1504/D | - | Metastability and the ECLinPS Family |
| AN1568/D | - | Interfacing Between LVDS and ECL |
| AN1672/D | - | The ECL Translator Guide |
| AND8001/D | - | Odd Number Counters Design |
| AND8002/D | _ | Marking and Date Codes |
| AND8020/D | _ | Termination of ECL Logic Devices |
| AND8066/D | _ | Interfacing with ECLinPS |
| AND8090/D | _ | AC Characteristics of ECL Devices |

PACKAGE DIMENSIONS

LQFP 64 LEAD EXPOSED PAD

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NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MM.
- 2.
- DATUM PLANE "E" IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING PLANE. 3.
- DATUM "X", "Y" AND "Z" TO BE DETERMINED AT DATUM PLANE DATUM "E". 4.
- 5. DIMENSIONS M AND L TO BE DETERMINED AT SEATING PLANE DATUM "T". 6.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 (0.010) PER SIDE. DIMENSIONS A AND B DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLAND "E".
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE MAXIMUM D DIMENSION 7. BY MORE THAN 0.08 (0.003). DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD OR PROTRUSION 0.07

^{(0.003).} 8. EXACT SHAPE OF EACH CORNER IS OPTIONAL.

| | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 10.00 BSC | | 0.394 BSC | |
| В | 10.00 BSC | | 0.394 BSC | |
| С | 1.35 | 1.45 | 0.053 | 0.057 |
| D | 0.17 | 0.27 | 0.007 | 0.011 |
| F | 0.45 | 0.75 | 0.018 | 0.030 |
| G | 0.50 BSC | | 0.020 BSC | |
| Н | 1.00 REF | | 0.039 BSC | |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| K | 0.05 | 0.15 | 0.002 | 0.006 |
| L | 12.00 BSC | | 0.472 BSC | |
| M | 12.00 BSC | | 0.472 BSC | |
| N | 0.20 | | 0.008 | |
| Р | 0 ° | 7 ° | 0 ° | 7° |
| R | 0 ° | | 0 ° | |
| S | | 1.60 | | 0.063 |
| ۷ | 11 ° | 13 ° | 11 ° | 13 ° |
| W | 11 ° | 13 ° | 11 ° | 13 ° |
| AA | 0.17 | 0.23 | 0.007 | 0.009 |
| AB | 0.09 | 0.16 | 0.004 | 0.006 |
| AC | 0.08 | | 0.003 | |
| AD | 0.08 | | 0.003 | |
| AE | 4.50 | 4.78 | 0.180 | 0.188 |
| AF | 4.50 | 4.78 | 0.180 | 0.188 |

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